NSN 5961-01-116-7580

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-116-7580 **Inclosure Material:** Metal **Overall Length:** 0.455 inches **Terminal Length:** 0.275 inches **Overall Diameter:** Between 0.355 inches and 0.370 inches **Internal Configuration:** Junction contact-double base **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Gold plated leads and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector to emitter, sustained and 60.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 0.50 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Dual transistor; junction pattern arrangement: npn **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No